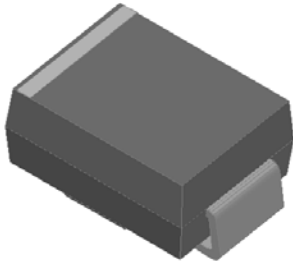


Surface Mount Super Fast Recovery Rectifier

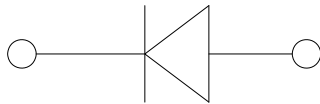


Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- High forward surge capability
- Super Fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Part no. with suffix "Q" means AEC-Q101 qualified

Typical Applications

For use in high frequency rectification of power supplies, inverters, converters, and freewheeling diodes for consumer, automotive and telecommunication.



Mechanical Data

- **Package:** DO-214AA (SMB)
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Cathode line denotes the cathode end

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	ES3ABQ	ES3BBQ	ES3CBQ	ES3DBQ	ES3FBQ	ES3GBQ	ES3HBQ	ES3JBQ
Device marking code			ES3AB	ES3BB	ES3CB	ES3DB	ES3FB	ES3GB	ES3HB	ES3JB
Repetitive peak reverse voltage	V _{RRM}	V	50	100	150	200	300	400	500	600
Average rectified output current @60Hz sine wave, resistance load, T _L (Fig.1)	I _o	A	3.0							
Surge(non-repetitive)forward current @60Hz half-sine wave,1 cycle Ta=25°C	I _{FSM}	A	100							
Storage temperature	T _{stg}	°C	-55 ~ +150							
Junction temperature	T _J	°C	-55 ~ +150							

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	ES3ABQ	ES3BBQ	ES3CBQ	ES3DBQ	ES3FBQ	ES3GBQ	ES3HBQ	ES3JBQ
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =3.0A	0.95			1.3		1.7		
Maximum reverse recovery time	T _{RR}	ns	I _F =0.5A, I _R =1.0A, I _{rr} =0.25A	35							
Typical junction capacitance	C _J	pF	V _R =4V, f=1 MHz	60							
Maximum DC reverse current at rated DC blocking voltage per diode @ V _{RM} =V _{RRM}	I _{RRM}	μA	T _a =25°C	5							
			T _a =125°C	100							



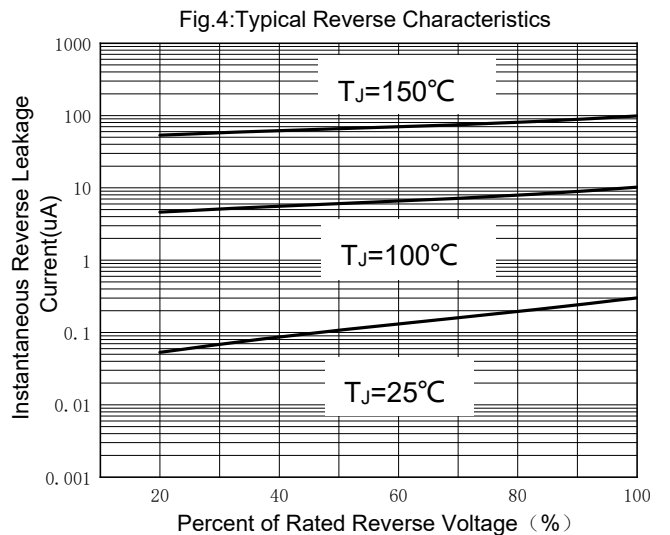
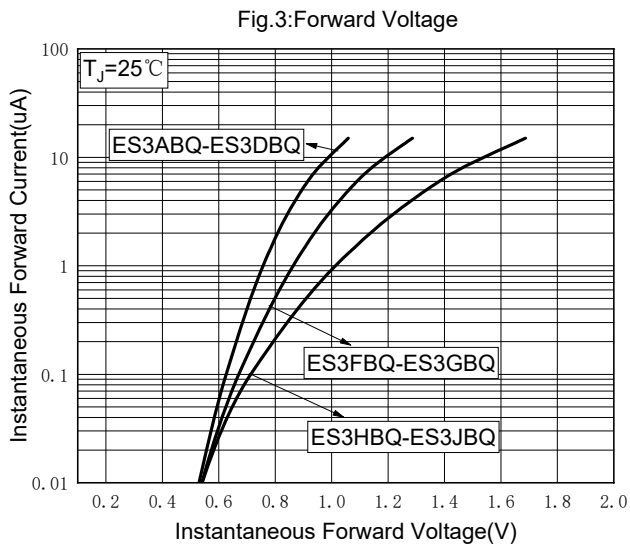
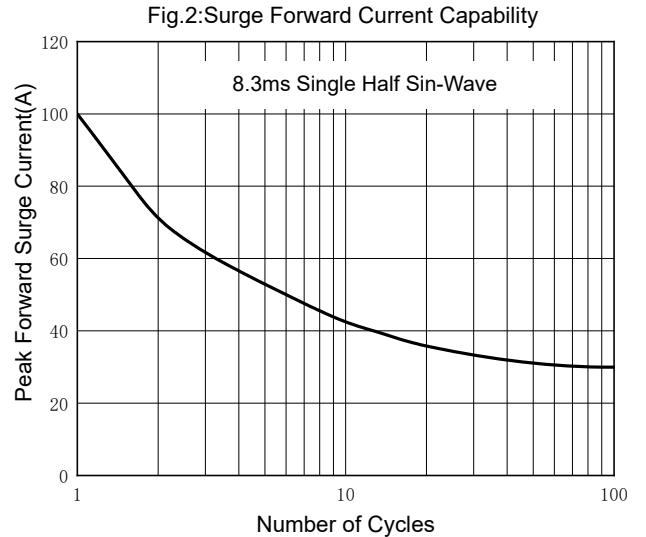
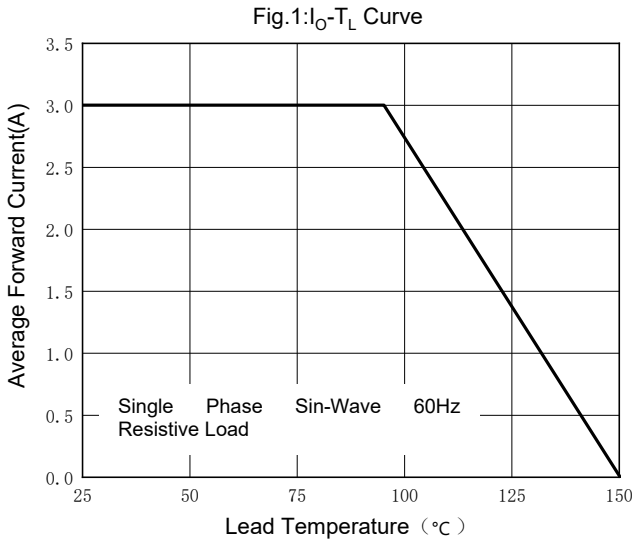
ES3ABQ THRU ES3JBQ

■ Thermal Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	ES3ABQ	ES3BBQ	ES3CBQ	ES3DBQ	ES3FBQ	ES3GBQ	ES3HBQ	ES3JBQ
Typical Thermal resistance	$R_{\theta J-A}$	$^\circ\text{C/W}$	65 ⁽¹⁾							
	$R_{\theta J-L}$		20 ⁽¹⁾							

Note:
 (1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.3" x 0.3" (8.0 mm x 8.0 mm) copper pad areas

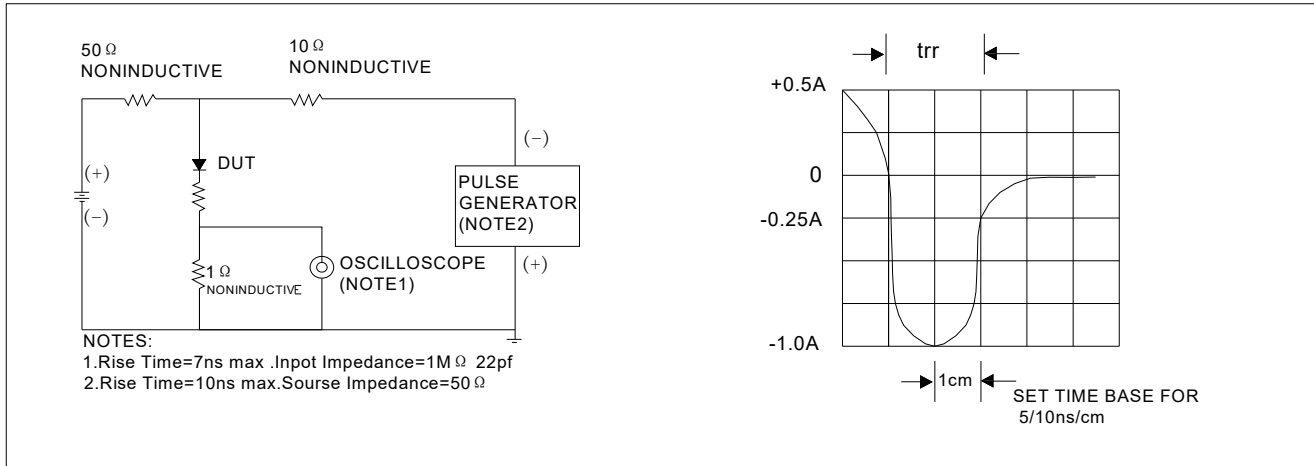
■ Characteristics (Typical)





ES3ABQ THRU ES3JBQ

Fig.5: Diagram of circuit and Testing wave form of reverse recovery time



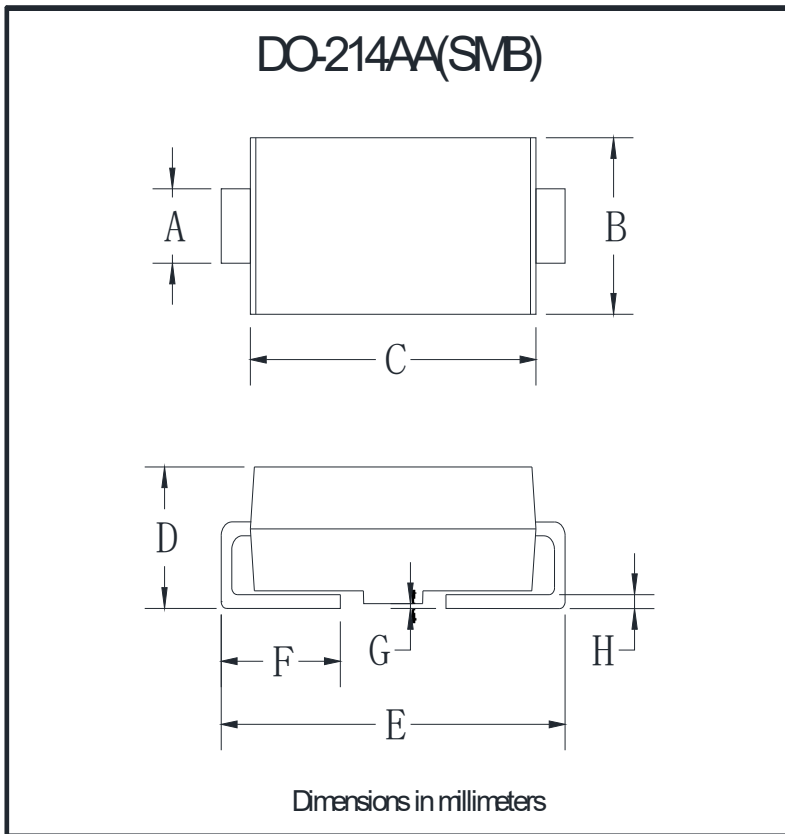
Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ES3ABQ-ES3JBQ	F1	Approximate 0.1003	3000	6000	48000	13" reel



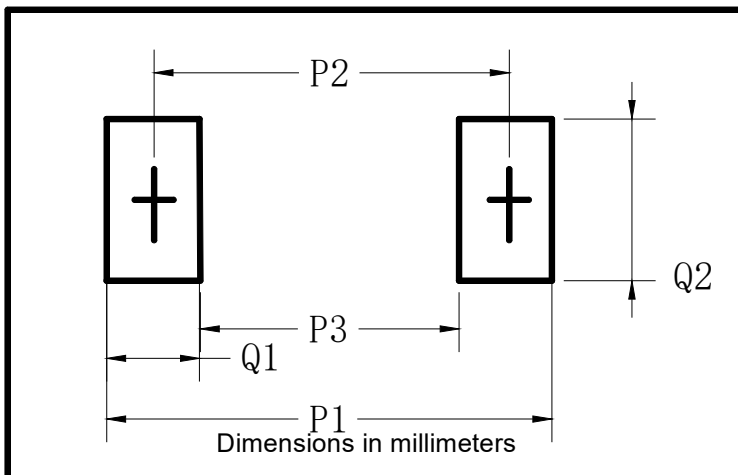
ES3ABQ THRU ES3JBQ

■ Outline Dimensions



DO-214AA(SMB)		
Dim	Min	Max
A	1.85	2.15
B	3.3	3.94
C	4.25	4.75
D	1.99	2.61
E	5.21	5.59
F	0.9	1.41
G	0.1	0.2
H	0.15	0.31

■ Suggested pad layout



DO-214AA(SMB)	
Dim	Millimeters
P1	6.8
P2	4.3
P3	1.8
Q1	2.5
Q2	2.3



ES3ABQ THRU ES3JBQ

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